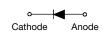


Vishay Semiconductors

Schottky Rectifier, 1.0 A





SMB

PRODUCT SUMMARY				
Package	SMB (DO-214AA)			
I _{F(AV)}	1 A			
V_{R}	15 V			
V _F at I _F	0.32 V			
I _{RM}	12 mA at 100 °C			
T _J max.	125 °C			
Diode variation	Single die			
E _{AS}	1 mJ			

FEATURES

- Ultralow forward voltage drop
- Optimized for OR-ing applications



- Guard ring for enhanced ruggedness and long term reliability
- 125 °C T_J operation (V_R < 5 V)
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-10BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	A		
V_{RRM}		15	V		
I _{FSM}	$t_p = 5 \mu s sine$	140	Α		
V _F	1.0 Apk, T _J = 125 °C	0.32	V		
T _J	Range	- 55 to 125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ015PbF	UNITS	
Maximum DC reverse voltage	V_{R}	15	V	
Maximum working peak reverse voltage	V_{RWM}	25		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _L = 84 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	140	A
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse		40	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.35	V
		2 A		0.44	
See fig. 1		1 A	T _J = 125 °C	0.32	
		2 A		0.40	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.5	- mA
See fig. 2	'RM ` ′	T _J = 100 °C		12	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J}$ maximum		-	V
Forward slope resistance	r _t				mΩ
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		390	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 0		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 55 to 150	C	
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C AM	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approximate weight			0.10	g	
Approximate weight			0.003	OZ.	
Marking device		Case style SMB (similar to DO-214AA)	V1	IC	

Notes

 $[\]frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

⁽²⁾ Mounted 1" square PCB



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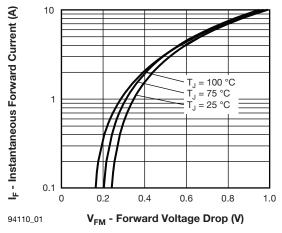


Fig. 1 - Maximum Forward Voltage Drop Characteristics

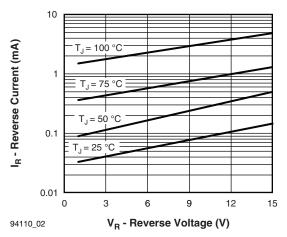


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

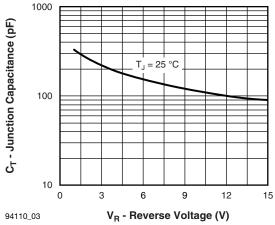


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

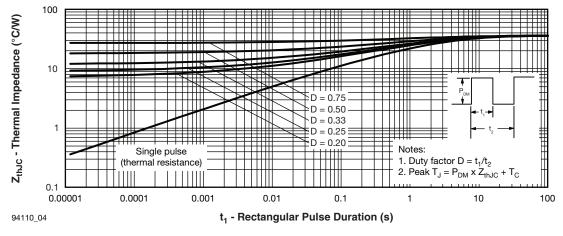


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Schottky Rectifier, 1.0 A



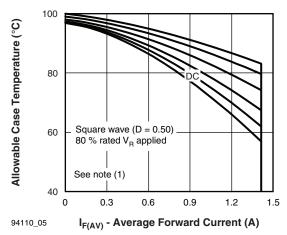


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

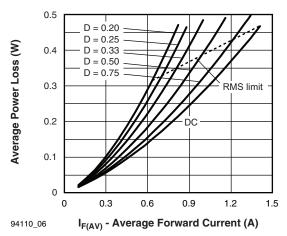


Fig. 6 - Forward Power Loss Characteristics

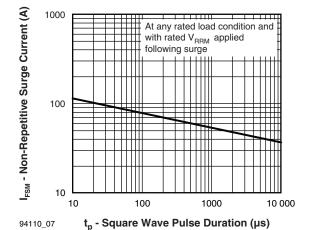


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

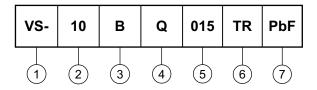


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ORDERING INFORMATION TABLE

Device code



1 - HPP product suffix

2 - Current rating

B = Single lead diode

4 - Q = Schottky "Q" series

- Voltage rating (015 = 15 V)

• None = Box (1000 pieces)

• TR = Tape and reel (3000 pieces)

7 - PbF = Lead (Pb)-free

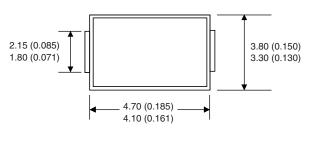
LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95017</u>			
Part marking information	www.vishay.com/doc?95029		
Dockgoing information	Tape and reel	www.vishay.com/doc?95034	
Packaging information	Bulk	www.vishay.com/doc?95397	
SPICE model		www.vishay.com/doc?95355	

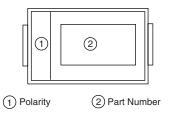


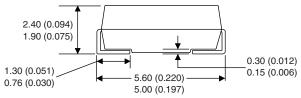
Vishay High Power Products

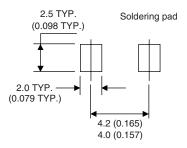
SMB

DIMENSIONS in millimeters (inches)













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